Hyperfast Rectifier, 30 A FRED Pt<sup>®</sup> G5



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### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	30 A				
V <sub>R</sub>	600 V				
V <sub>F</sub> at I <sub>F</sub> at 125 °C	1.3 V				
T <sub>J</sub> max.	175 °C				
t <sub>rr</sub> (typ.)	22 ns				
Package	TO-220AC 2L				
Circuit configuration	Single				

### FEATURES

- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- Meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV battery charging stations and high frequency stages of UPS applications.

### **MECHANICAL DATA**

Case: TO-220AC 2L

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage	V <sub>RRM</sub>		600	V			
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 106 °C, D = 0.50	30				
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_{C}$ = 25 °C, $t_{p}$ = 10 ms, sine wave	310	А			
Repetitive peak forward current	I <sub>FRM</sub>	T <sub>C</sub> = 106 °C, D = 0.50, f = 20 kHz	60				
Operating junction and storage temperature	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-		
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 30 A	-	1.6	2.1	V	
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 125 °C	-	1.3	-		
Deverse leakers eurrent	I <sub>R</sub>	$V_{R} = V_{R}$ rated	-	-	20		
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA	
Junction capacitance	CT	V <sub>R</sub> = 200 V	-	36	-	pF	
Series inductance	L <sub>S</sub>	Measured to lead 5 mm from package body	-	8	-	nH	

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# Vishay Semiconductors

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J$ = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A,} dI_F/dt =$	$I_F = 1.0 \text{ A,} dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		22	-		
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	39	-	ns	
		T <sub>J</sub> = 125 °C		-	50	-		
Peak recovery current		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 20 A dI <sub>F</sub> /dt = 1000 A/µs	-	14	-	A	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	$V_{\rm R} = 400 \text{ V}$	-	24	-		
Reverse recovery charge	0	T <sub>J</sub> = 25 °C		-	253	-	nC	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	785	-		
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 30 A dI <sub>F</sub> /dt = 1000 A/µs V <sub>R</sub> = 400 V	-	41	-	ns	
Reverse recovery time	L <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	56	-		
Pools recovery ourrent		T <sub>J</sub> = 25 °C		-	16	-	A	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	27	-		
Poverse receiver charge	0	T <sub>J</sub> = 25 °C		-	306	-		
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	952	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction-to-case	R <sub>thJC</sub>		-	-	1.3	°C/W		
Weight			-	2.0	-	g		
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C		
Marking device		Case style: TO-220AC 2L	E5TX3006					

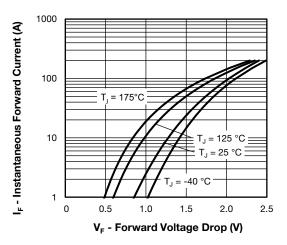


Fig. 1 - Typical Forward Voltage Drop Characteristics

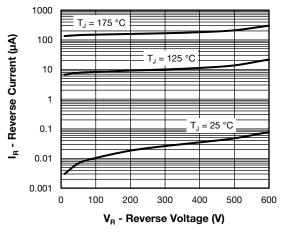
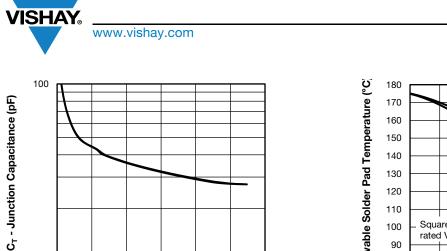
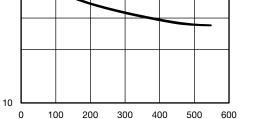
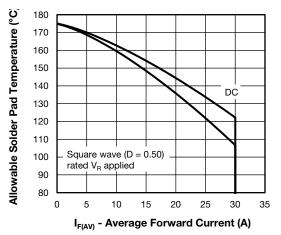


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage





V<sub>R</sub> - Reverse Voltage (V) Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



VS-E5TX3006-M3

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Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

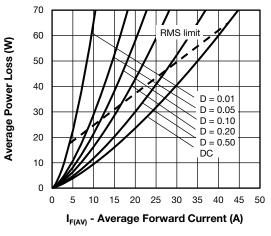


Fig. 5 - Average Power Loss vs. Average Forward Current

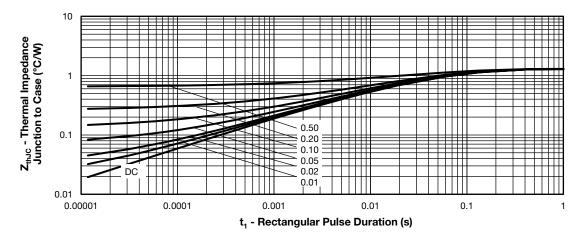


Fig. 6 - Thermal Impedance ZthJC - Characteristics



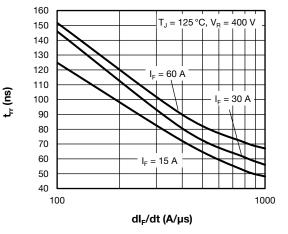


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

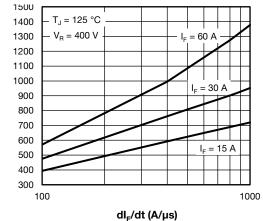


Fig. 8 - Typical Reverse Recovery Charge vs. dl<sub>F</sub>/dt

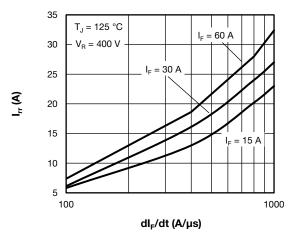


Fig. 9 - Typical Reverse Recovery Current vs. dl<sub>F</sub>/dt

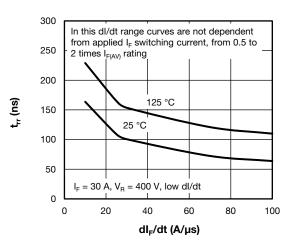
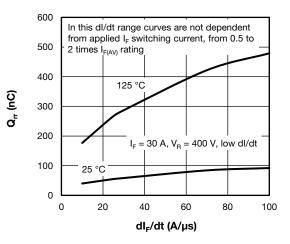


Fig. 10 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt





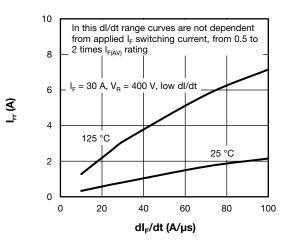


Fig. 12 - Typical Reverse Recovery Current vs. dl<sub>F</sub>/dt

Qrr (nC)

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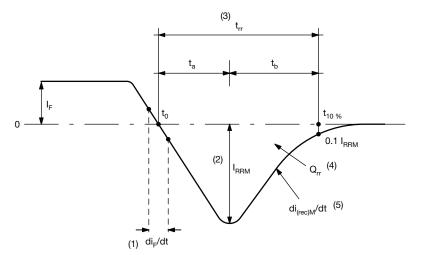


Fig. 13 - Reverse Recovery Waveform and Definitions

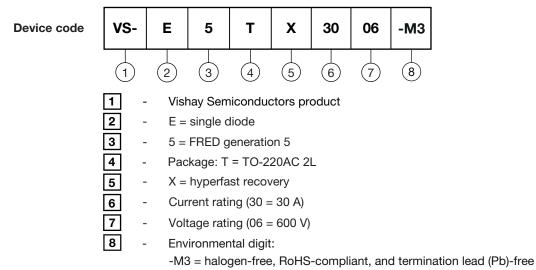
#### Notes

- <sup>(1)</sup> di<sub>F</sub>/dt rate of change of current through zero crossing
- <sup>(2)</sup> I<sub>RRM</sub> peak reverse recovery current
- $^{(3)}$  t<sub>rr</sub> reverse recovery time measured from t<sub>0</sub>, crossing point of negative going I<sub>F</sub>, to point t<sub>10%</sub>, 0.1 I<sub>RRM</sub>
- $^{(4)}~Q_{rr}$  area under curve defined by  $t_0$  and  $t_{10\ \%}$

$$Q_{rr} = \int\limits_{t_0}^{t_{10\,\%}} I(t) dt$$

 $^{(5)}$  di<sub>(rec)</sub>M/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

### **ORDERING INFORMATION TABLE**



ORDERING INFORMATION (Example)						
PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION						
VS-E5TX3006-M3	50	Antistatic plastic tubes				

LINKS TO RELATED DOCUMENTS				
www.vishay.com/doc?96156				
www.vishay.com/doc?95391				
www.vishay.com/doc?96918				

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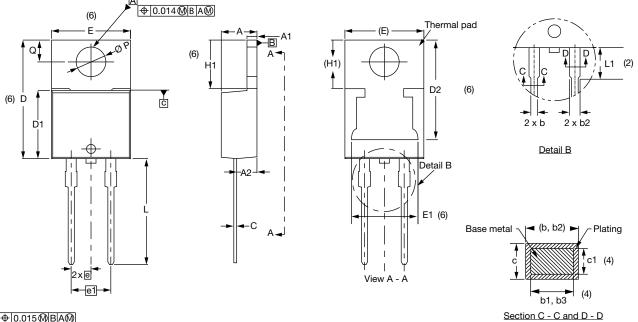
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**TO-220AC 2L** 

### **DIMENSIONS** in millimeters and inches



⊕0.015@BA@



SYMBOL	MILLIN	IETERS	INC	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

Conforms to JEDEC	® outline TO-220AC

SYMBOL	MILLIN	MILLIMETERS		INCHES		
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D2	11.68	13.30	0.460	0.524	6, 7	
E	10.11	10.51	0.398	0.414	3, 6	
E1	6.86	8.89	0.270	0.350	6	
е	2.41	2.67	0.095	0.105		
e1	4.88	5.28	0.192	0.208		
H1	6.09	6.48	0.240	0.255	6	
L	13.52	14.02	0.532	0.552		
L1	3.32	3.82	0.131	0.150	2	
ØР	3.54	3.91	0.139	0.154		
Q	2.60	3.00	0.102	0.118		

#### Notes

 $^{(1)}\,$  Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension and finish uncontrolled in L1

<sup>(4)</sup> Dimension b1, b3, and c1 apply to base metal only

(5) Controlling dimensions: inches

- <sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2, and E1
- <sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> TO-220, except D2

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<sup>(3)</sup> Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body



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